

ADVERTISING & TRADING COMPANIES

Group 21 Unit

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RM	-	"40% Tunneling Magnetoresistance After Anneal at 380°C for Tunnel Junctions with Thin Oxide Interface Layers," by Shang et al., J. of Appl. Physics, Vol. 89, No. 11, June 1, 2001, pp. 6665-6667.
RM	-	"Oxygen as a Surfactant in the Growth of Giant Magnetoresistance Spin Valves," by W. F. Egelhoff, Jr. et al., J. of Appl. Physics, Vol. 82, No. 12, Dec. 15, 1997, pp. 6142-6151.

07/11/2006

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.